MINIATURE HIGH VOLTAGE GLASS PASSIVATED JUNCTION PLASTIC RECTIFIER

Reverse Voltage: 2000 to 4000 V

Forward Current: 0.25 A

Features

- · Glass passivated junction
- · High current capability
- · High surge current capability
- High reliability
- · Low reverse current
- · Low forward voltage drop

Mechanical Data

· Case: DO-41 Molded plastic

• Epoxy: UL 94V-0 rate flame retardant

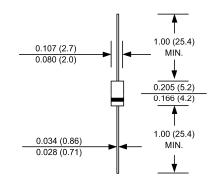
• Lead: Axial lead solderable per MIL-STD-202

Method 208 guaranteed

• Polarity: Color band denotes cathode end

· Mounting position: Any

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Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	GP02-20	GP02-25	GP02-30	GP02-35	GP02-40	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	2000	2500	3000	3500	4000	V
Maximum RMS Voltage	V_{RMS}	1400	1750	2100	2450	2800	V
Maximum DC Blocking Voltage	V_{DC}	2000	2500	3000	3500	4000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length $T_a = 55$ °C	I _{F(AV)}	0.25					Α
Peak Forward Surge Current 8.3 ms. Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	15					Α
Maximum Forward Voltage at 1A	V _F	3					V
Maximum Reverse Current at Rated at T_a = 25 °C DC Blocking Voltage at T_a = 100 °C	I _R	5 50					μΑ
Maximium Reverse Recovery Time 1)	t _{rr}	2					μs
Typical Junction Capacitance 2)	CJ	3					pF
Typical Thermal Resistance 3)	$R_{\theta JA}$	130					°C/W
Junction Temperature Range	T _J	- 65 to + 175					°C
Storage Temperature Range	Ts	- 65 to + 175					°C

 $^{^{1)}}$ Reverse recovery test conditions: I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A

³⁾ Thermal resistance from junction to ambient at 0.375"(9.5mm) Lead Lengths, P.C. board mounted.



SEMTECH ELECTRONICS LTD.

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Dated: 10/10/2007

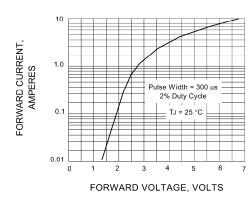
²⁾ Measured at 1 MHz and applied reverse voltage of 4 VDC

FIG. 1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT 0.25 AVERAGE FORWARD OUTPUT CURRENT, AMPERES 0.20 0.10 0.05 0 100 125 150 CASE TEMPERATURE, (°C)

FIG. 2 - MAXIMUM NON-REPETITIVE PEAK PEAK FORWARD SURGE CURRENT, FORWARD SURGE CURRENT 15 8.3ms SINGLE HALF SINE-WAVE 12 AMPERES 6 3 20 40 60 NUMBER OF CYCLES AT 60Hz

FIG. 3 - TYPICAL FORWARD CHARACTERISTICS

FIG. 4 - TYPICAL REVERSE CHARACTERISTICS



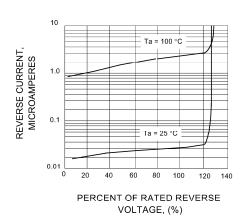


FIG 5. - TYPICAL JUNCTION CAPACITANCE JUNCTION CAPACITANCE, (pF) 6 5 TJ = 25 °C f = 1MHz Vsig = 50MVp-p 4 3 2 0.2 20 REVERSE VOLTAGE, VOLTS







